

TOSHIBA TRANSISTOR   SILICON NPN EPITAXIAL TYPE (PCT PROCESS)

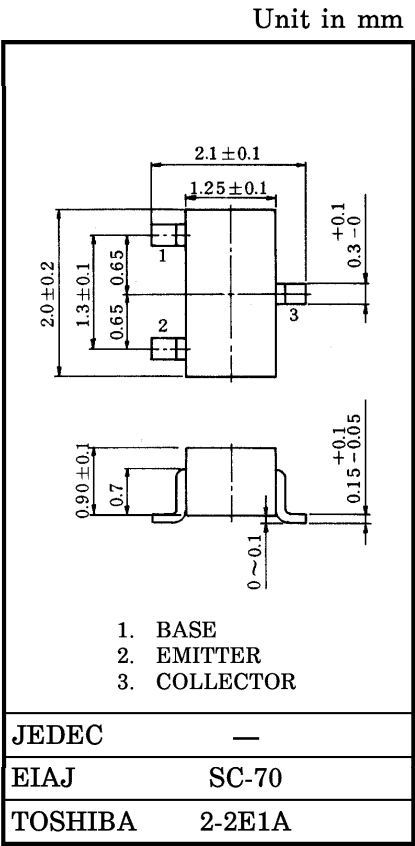
2SC4667

ULTRA HIGH SPEED SWITCHING APPLICATIONS.  
COMPUTER, COUNTER   APPLICATIONS.

- High Transition Frequency   :  $f_T=400\text{MHz}$  (Typ.)
- Low Saturation Voltage       :  $V_{CE(sat)}=0.3\text{V}$  (Max.)
- High Speed Switching Time :  $t_{stg}=15\text{ns}$  (Typ.)

MAXIMUM RATINGS ( $T_a = 25^{\circ}\text{C}$ )

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	$V_{CBO}$	40	V
Collector-Emitter Voltage	$V_{CEO}$	15	V
Emitter-Base Voltage	$V_{EBO}$	5	V
Collector Current	$I_C$	200	mA
Base Current	$I_B$	40	mA
Collector Power Dissipation	$P_C$	100	mW
Junction Temperature	$T_j$	125	$^{\circ}\text{C}$
Storage Temperature Range	$T_{stg}$	$-55\sim 125$	$^{\circ}\text{C}$



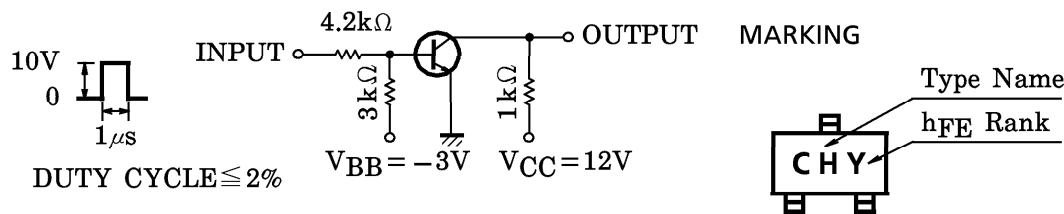
Weight : 0.006g

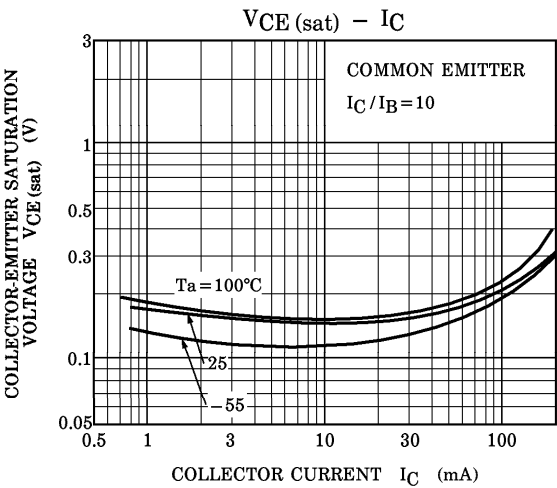
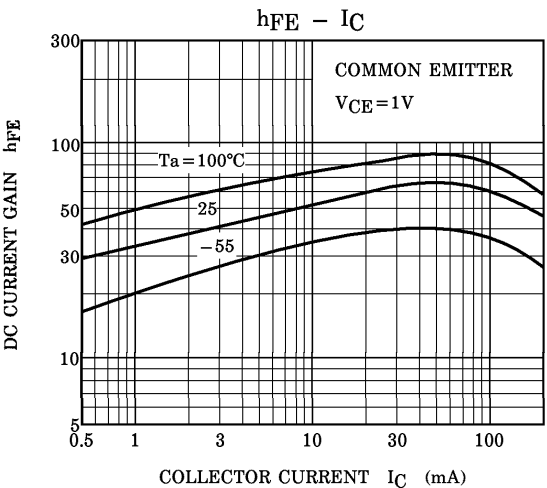
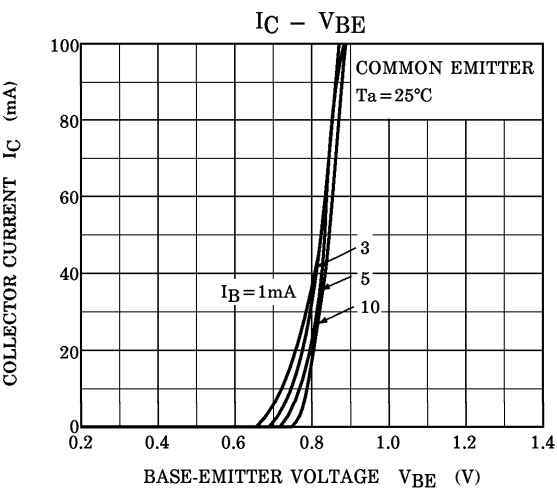
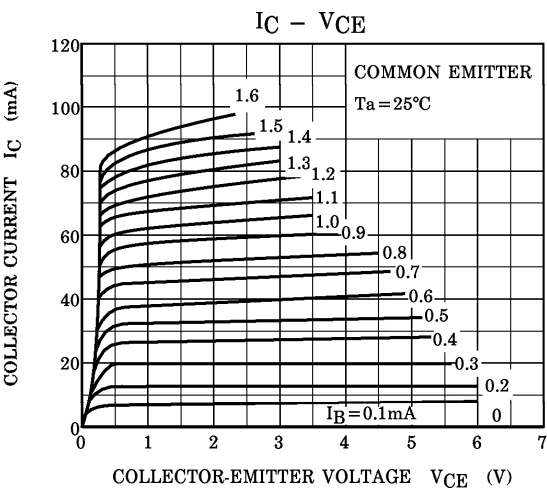
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

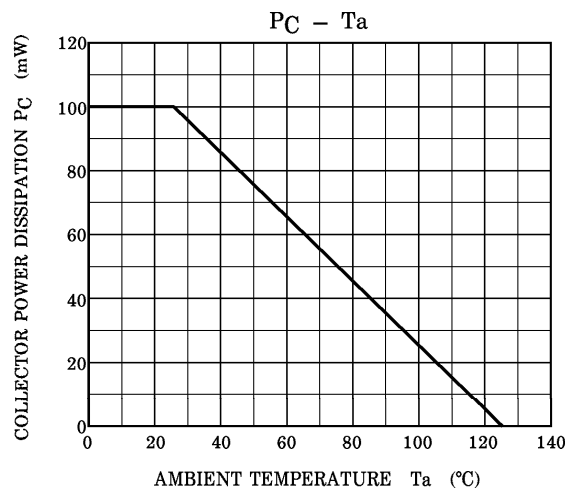
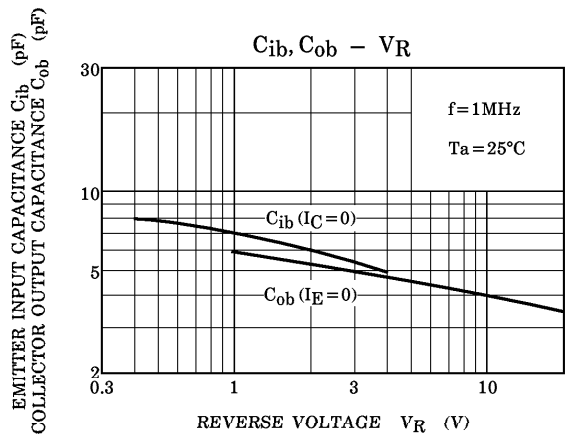
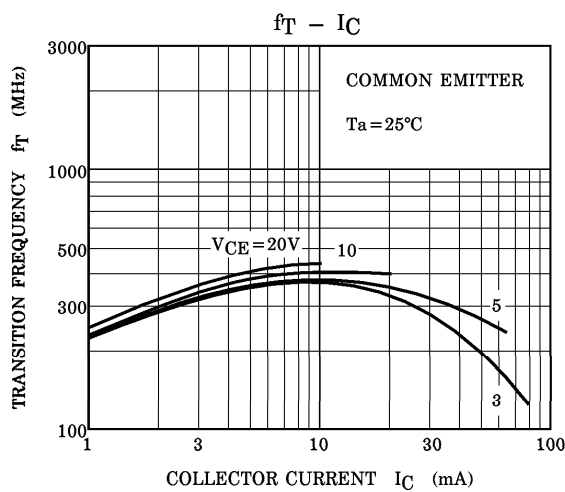
CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current		ICBO	V <sub>CB</sub> = 40V, I <sub>E</sub> = 0	—	—	0.1	μA
Emitter Cut-off Current		IEBO	V <sub>EB</sub> = 5V, I <sub>C</sub> = 0	—	—	0.1	μA
DC Current Gain	h <sub>FE</sub> (1) (Note 1)		V <sub>CE</sub> = 1V, I <sub>C</sub> = 10mA	40	—	240	
	h <sub>FE</sub> (2)		V <sub>CE</sub> = 1V, I <sub>C</sub> = 100mA	20	—	—	
Collector-Emitter Saturation Voltage		V <sub>CE</sub> (sat)	I <sub>C</sub> = 20mA, I <sub>B</sub> = 1mA	—	—	0.3	V
Base-Emitter Saturation Voltage		V <sub>BE</sub> (sat)	I <sub>C</sub> = 20mA, I <sub>B</sub> = 1mA	—	—	1.0	V
Transition Frequency		f <sub>T</sub>	V <sub>CE</sub> = 10V, I <sub>C</sub> = 10mA	200	400	—	MHz
Collector Output Capacitance		C <sub>ob</sub>	V <sub>CB</sub> = 10V, I <sub>E</sub> = 0, f = 1MHz	—	4	6	pF
Switching Time	Turn-on Time	t <sub>on</sub>	(Note 2)	—	70	—	ns
	Storage Time	t <sub>stg</sub>		—	15	—	
	Turn-off Time	t <sub>off</sub>		—	30	—	

Note 1 : h<sub>FE</sub>(1) Classification     R : 40~80, O : 70~140, Y : 120~240

Note 2 : SWITCHING TIME TEST CIRCUIT







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